











SLVS732G -JULY 2010-REVISED APRIL 2017

TL4242-Q1



TL4242-Q1 Adjustable LED Driver

Features

- Qualified for Automotive Applications
- AEC-Q100 Test Guidance With the Following Results:
 - Device Temperature Grade 2: -40°C to 105°C Ambient Operating Temperature Range for WSON package
 - Device Temperature Grade 1: -40°C to 125°C Ambient Operating Temperature Range for TO-263 package
 - Device HBM ESD Classification Level H1C
 - Device CDM ESD Classification Level C3B
- Adjustable Constant Current up to 500 mA (±5%)
- Wide Input-Voltage Range up to 42 V
- Low Dropout Voltage
- Open-Load Detection
- Overtemperature Protection
- Short-Circuit Proof
- Reverse-Polarity Proof

Applications

Automotive LED Lighting Applications Including:

- Rear Light
- **Daytime Running Light**
- Fog Light
- Position Light
- Interior Light
- Stop or Tail Light

3 Description

The TL4242-Q1 device is an integrated adjustable constant-current source, driving loads up to 500 mA. One can adjust the output current level through an external resistor. The device design is for supplying high-power LEDs (for example, OSRAM Dragon LA W57B) under the severe conditions of automotive applications, resulting in constant brightness and extended LED lifetime. The device comes in the DRJ (WSON) and KTT (TO-263) package. Protection circuits prevent damage to the device in case of overload, short-circuit, reverse polarity, and overheat. The device provides the connected LEDs protection against reverse polarity as well as excess voltages up to 45 V.

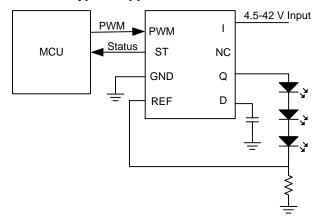
The integrated PWM input of the TL4242-Q1 device permits LED brightness regulation by pulse-width modulation (PWM). The high-input impedance of the PWM input allows operating the LED driver as a protected high-side switch.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TL4242-Q1	TO-263 (7)	10.00 mm × 9.25 mm
	WSON (8)	4.00 mm × 4.00 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Typical Application Schematic





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4 Revision History

C	hanges from Revision F (January 2015) to Revision G	Page
•	Changed the pinout drawings	4
•	Changed all occurrences in the data sheet of QFN and SFM to WSON and TO-263, respectively	4
•	Changed format of Pin Functions table	4
•	Changed the condition statement for the Electrical Characteristics table	6
•	Added layout diagram for the TO-263 package	15
•	Added Receiving Notification of Documentation Updates and Community Resources sections to the data sheet	16
_		
C	hanges from Revision E (July 2013) to Revision F	Page

•	Added Pin Configuration and Functions section, ESD Ratings table, Feature Description section, Device Functional
	Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device
	and Documentation Support section, and Mechanical, Packaging, and Orderable Information section

Changes from Revision D (May 2013) to Revision E	Page
Added new graph to Typical Characteristics	-

Changes from Revision C (October 2012) to Revision D				
•	Changed minimum storage temperature to -55°C	5		

CI	nanges from Revision B (September 2012) to Revision C	Page
•	Added Stoplight and Taillight Application section	12
•	Added Thermal Considerations section	18
•	Added PCB Design Guideline section	18



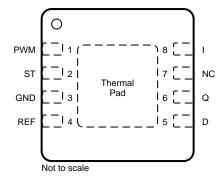


Cł	Changes from Revision A (August, 2012) to Revision B		ge
•	Manually appended mechanical data, thermal pad data, and package option addendum		1

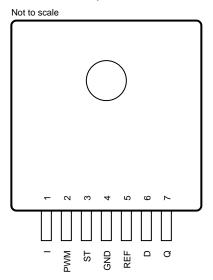


5 Pin Configuration and Functions

DRJ Package 8-Pin WSON With Exposed Thermal Pad Top View



KTT Package 7-Pin TO-263 With Exposed Thermal Pad Top View



Pin Functions

PIN					
NAME	N	0.	I/O	DESCRIPTION	
NAME	DRJ KTT				
D	5	6	I	Status delay. To set status reaction delay, connect to GND with a capacitor. For no delay, leave open.	
GND	3	4	_	Ground	
1	8	8 1		Input. Connect directly to GND as close as possible to the device with a 100-nF ceramic capacitor.	
NC	7	_	_	No internal connection	
PWM	1	2	- 1	Pulse-width modulation input. If not used, connect to the I pin.	
Q	6	7	0	Output	
REF	4	5	I	Reference input. Connect to a shunt resistor.	
ST	2	3	0	Status output. Open-collector output. Connect to an external pullup resistor (R _{PULLUP} \geq 4.7 k Ω).	
Thermal pad	_	_	_	Solder the thermal pad directly to the PCB. Connect to ground or leave floating.	

Product Folder Links: *TL4242-Q1*

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6 Specifications

6.1 Absolute Maximum Ratings

over operating ambient temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
Supply voltage ⁽²⁾ , V _{CC}		-42	45	V
	D	-0.3	7	
nput voltage, V _I	PWM	-40	40	V
	REF	-1	16	
Putnut voltago V	Q	-1	41	V
Output voltage, V _O	ST	-0.3	-40 40 -1 16 -1 41 -0.3 40 ±1 ±2	
	PWM		±1	
Output current, I _O	REF		±2	mA
	ST		±5	1
Virtual-junction temperature, T _J	,	-40	150	°C
Storage temperature, T _{stg}		-55	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

	-			VALUE	UNIT
DRJ Pack	kage				
		Human body model (HBM), per AEC	C Q100-002 ⁽¹⁾	±1500	
M	Floatroatatia diaabaraa	Charged device model (CDM), per	Corner pins (1, 4, 5, and 8)	±1000	V
V _(ESD)	Electrostatic discharge	AEC Q100-011	Other pins	±1000	V
		Machine model (MM) AEC-Q100 Classification Level M3		±200	
KTT Pack	kage				
		Human body model (HBM), per AEC	C Q100-002 ⁽¹⁾	±1500	
V _(ESD)	Electrostatio discharge	Charged device model (CDM), per	Corner pins (1 and 7)	±1000	V
	Electrostatic discharge	AEC Q100-011	Other pins	±1000	
		Machine model (MM) AEC-Q100 Cla	assification Level M3	±200	

⁽¹⁾ AEC Q100-002 indicates HBM stressing is done in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 Recommended Operating Conditions

			MIN	MAX	UNIT
V_{CC}	CC Supply voltage				V
V_{ST}	T Status (ST) output voltage				V
V_{PWM}	PWM voltage	0	40	V	
C _D	Status delay (D) capacitance	0	2.2	μF	
R _{REF}	Reference (REF) resistor	0	10	Ω	
_		Operating ambient temperature WSON TO-263		105	00
T _A	Operating ambient temperature			125	°C
T _J	Operating junction temperature		-40	150	°C

⁽²⁾ All voltage values are with respect to the network ground terminal.



6.4 Thermal Information

		TL424	TL4242-Q1		
	THERMAL METRIC ⁽¹⁾	DRJ (WSON)	KTT (TO- 263)	UNIT	
		8 PINS	7 PINS		
$R_{\theta JA}$	Junction-to-ambient thermal resistance	39	31.6	°C/W	
$R_{\theta JCtop}$	Junction-to-case (top) thermal resistance	31.5	34.7	°C/W	
$R_{\theta JB}$	Junction-to-board thermal resistance	15.5	8.2	°C/W	
ΨЈТ	Junction-to-top characterization parameter	0.3	0.7	°C/W	
ΨЈВ	Junction-to-board characterization parameter	15.6	8.2	°C/W	
$R_{\theta JCbot}$	Junction-to-case (bottom) thermal resistance	1.8	0.7	°C/W	

⁽¹⁾ For more information about traditional and new thermal metrics, see Semiconductor and IC Package Thermal Metrics

6.5 Electrical Characteristics

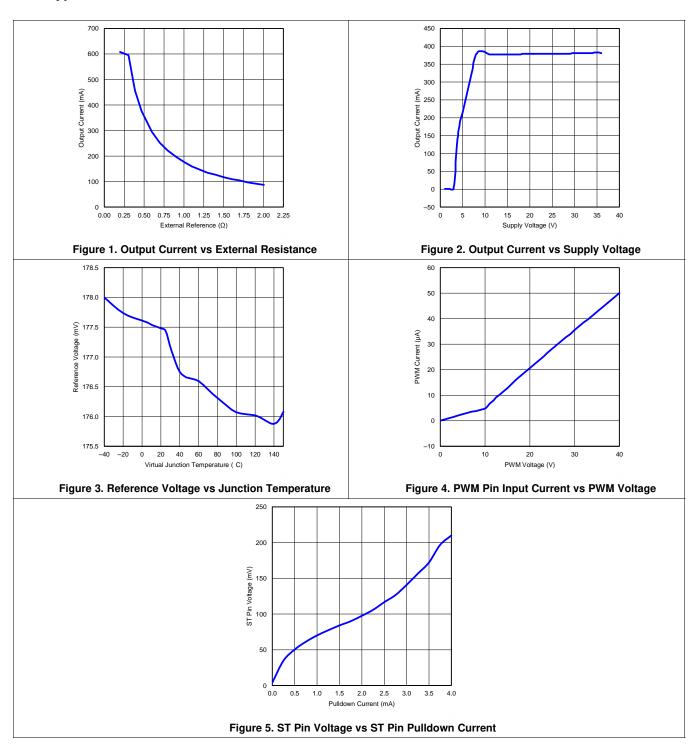
over recommended operating ambient temperature range, $V_I = 13.5 \text{ V}$, $R_{REF} = 0.47 \Omega$, $V_{PWM,H}$, $T_J = -40^{\circ}\text{C}$ to 150°C, all voltages with respect to ground (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OVERALL	DEVICE				•	
I _{qL}	Supply current	V _Q = 6.6 V		12	22	mA
I _{qOFF}	Supply current, off mode	PWM = L, T _J < 85°C		0.1	2	μА
OUTPUT						
		$V_Q - V_{REF}^{(1)} = 6.6 \text{ V}$	357	376	395	
		$V_Q - V_{REF} = 6.6 \text{ V}, R_{REF} = 1 \Omega$	168	177	185	
I_Q	Output current	$V_{Q} - V_{REF} = 6.6 \text{ V}, R_{REF} = 0.39 \Omega$	431	454	476	mA
		$V_Q - V_{REF} = 5.4 \text{ V to } 7.8 \text{ V}, V_I = 9 \text{ V}$ to 16 V	357	376	395	
I_{Qmax}	Output current limit	$R_{REF} = 0 \Omega$		600		mA
V_{dr}	Drop voltage	I _Q = 300 mA		0.35	0.7	V
PWM INPU	JT					
$V_{\text{PWM},H}$	High-level PWM voltage		2.6			V
$V_{\text{PWM,L}}$	Low-level PWM voltage				0.7	V
$I_{PWM,H}$	High-level PWM input current	V _{PWM} = 5 V		220	500	μА
$I_{PWM,L}$	Low-level PWM input current	$V_{PWM} = 0 V$	-1		1	μΑ
t _{PWM,ON}	Delay time, turnon	70% of I _{Qnom} , see Figure 7	0	15	40	μS
t _{PWM,OFF}	Delay time, turnoff	30% of I _{Qnom} , see Figure 7	0	15	40	μS
REFEREN	CE (REF)					
V_{REF}	Reference voltage	$R_{REF} = 0.39 \Omega$ to 1 Ω	168	177	185	mV
I _{REF}	Reference input current	V _{REF} = 180 mV	-1	0.1	1	μА
STATUS C	OUTPUT (ST)					
V_{IQL}	Lower status-switching threshold	ST = L	15	25		mV
V_{IQH}	Upper status-switching threshold	ST = H		30	40	mV
V_{STL}	Low-level status voltage	I _{ST} = 1.5 mA			0.4	V
I _{STLK}	Leakage current	V _{ST} = 5 V			5	μА
STATUS D	DELAY (D)				•	
t _{STHL}	Delay time, status reaction	$C_D = 47 \text{ nF, ST H} \rightarrow L$	6	10	14	ms
t _{STLH}	Delay time, status release	$C_D = 47 \text{ nF, ST L} \rightarrow H$		10	20	μS

⁽¹⁾ $V_Q - V_{REF}$ equals the forward voltage sum of the connected LEDs (see *Typical Application Schematic*).



6.6 Typical Characteristics



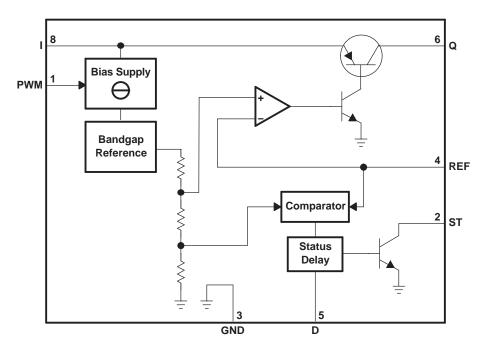


7 Detailed Description

7.1 Overview

The TL4242-Q1 device is an integrated adjustable constant-current source, driving loads up to 500 mA. The current can be set by an external resistor. And the load current can be modulated by a PWM input. The TL4242-Q1 device integrates protections such as open load, overtemperature, and reverse polarity.

7.2 Functional Block Diagram



7.3 Feature Description

The TL4242-Q1 device is an integrated adjustable constant-current source driving loads up to 500 mA. The TL4242-Q1 device is qualified for automotive applications. The output current level can be adjusted via an external resistor. Protection circuits prevent damage to the device in case of overload, short-circuit, reverse polarity, and overtemperature. The connected LEDs are protected against reverse polarity as well as overvoltages up to 45 V. The integrated PWM input of the TL4242-Q1 device permits LED brightness regulation by pulse-width modulation. Due to the high input impedance of the PWM input, the LED driver can be operated as a protected high-side switch.

The external shunt resistor in the ground path of the connected LEDs senses the LED current. A regulation loop holds the voltage drop at the shunt resistor at a constant level of 177 mV (typical). The selection of the shunt resistance, R_{REF} , sets the constant-current level. Calculate the typical output current using Equation 1:

$$I_{Q,typ} = \frac{V_{REF}}{R_{REF}} \tag{1}$$

where V_{REF} is the reference voltage (typically 177 mV) (see *Electrical Characteristics*). The equation applies for $R_{REF} = 0.39 \ \Omega$ to 10 Ω .

The output current is shown as a function of the reference resistance in Equation 1. With the PWM input, one can regulate the LED brightness through the duty cycle. Also, PWM = L sets the TL4242-Q1 device in sleep mode, resulting in a very low current consumption of < 1 μ A (typical). The high impedance of the PWM input (see Figure 4) permits the use of the PWM pin as an enable input.



7.4 Device Functional Modes

7.4.1 Pulse-Width Modulation (PWM)

In general applications, PWM can be used to control the TL4242-Q1 device as a high-side driver. High level enables the device. Low level disables the device. In LED lighting, PWM input provides a convenient way to control the brightness of the LED load. Due to the high input impedance of the PWM input, the LED driver can be operated as a protected high-side switch.

7.4.2 Status Output (ST)

The ST pin is an open-collector output. Connect the pin to an external pullup resistor ($R_{PULLUP} \ge 4.7 \text{ k}\Omega$). This output provides information of open-load and overtemperature faults.

7.4.3 Reference (REF)

REF is used to set load current. In applications, the load current is sensed by a resistor in series with the load. The voltage on the REF pin is regulated at 177 mV during normal operation. Therefore, the current of the load is determined by V_{REF} / R_{SENSE} .



8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The TL4242-Q1 device is usually used in the automotive lighting applications. A microcontroller is usually used to generate PWM waveform to dimming the LED.

8.2 Typical Applications

8.2.1 Application Circuit

Figure 6 shows a typical application with the TL4242-Q1 LED driver. A supply current adjusted by the R_{REF} resistor drives the three LEDs, preventing brightness variations due to forward voltage spread of the LEDs. An appropriate duty cycle applied to the PWM pin can compensate through software for the luminosity spread arising from the LED production process. Therefore, it is not necessary to select LEDs for forward voltage or luminosity classes. The minimum supply voltage should be equal to or greater than the sum of the LED forward voltages, the TL4242-Q1 drop voltage (maximum 0.7 V at an LED current of 300 mA), and the maximum voltage drop at the shunt resistor R_{REF} of 185 mV.

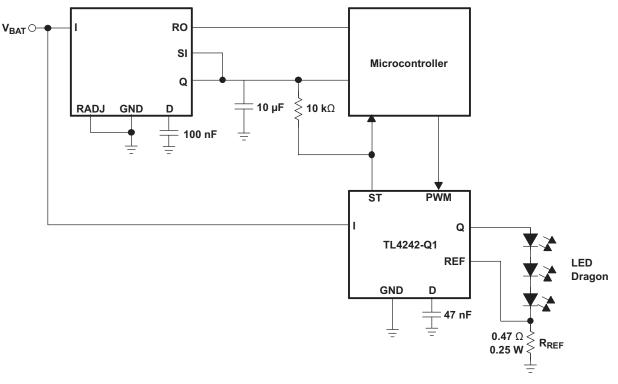


Figure 6. Application Circuit

8.2.1.1 Design Requirements

DESIGN PARAMETER	EXAMPLE VALUE
R _{REF}	0.47 Ω



8.2.1.2 Detailed Design Procedure

The status output of the LED driver (ST) detects an open-load condition, enabling supervision of correct LED operation. A voltage drop at the shunt resistor (R_{REF}) below 25 mV (typical) detects an LED failure. In this case, the status output pin (ST) goes low after a delay time adjustable by an optional capacitor connected to pin D.

Figure 7 shows the functionality and timing of ST and PWM. One can adjust the status delay through the capacitor connected to pin D. Delay time scales linearly with the capacitance, C_D :

$$t_{STHL,typ} = \frac{C_D}{47 \text{ nF}} \times 10 \text{ ms}$$
 (2)

$$t_{\text{STLH,typ}} = \frac{C_{\text{D}}}{47 \, \text{nF}} \times 10 \, \mu \text{s} \tag{3}$$

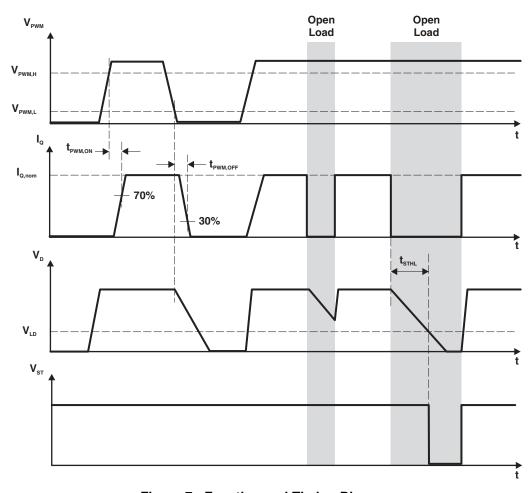
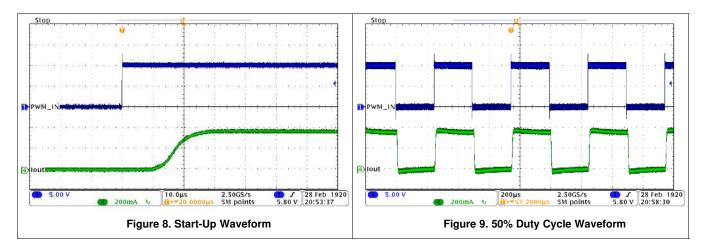


Figure 7. Function and Timing Diagram

Product Folder Links: TL4242-Q1

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8.2.1.3 Application Curves



8.2.2 Stoplight and Taillight Application

For many automobiles, the same set of LEDs illuminates both taillights and stop lights. Thus, the LEDs must operate at two different brightness levels, full brightness for the stoplight and 10% to 25% brightness for the taillight. The easiest way to achieve the different brightness is dimming by pulse-width modulation (PWM), which holds the color spectrum of the LED over its whole brightness range. The maximum current that passes through the LED is programmable by sense resistor $R_{\rm BFF}$.

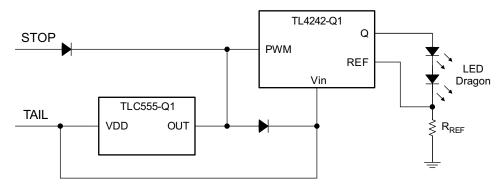


Figure 10. Stoplight and Taillight Application Circuit

8.2.2.1 Design Requirements

DESIGN PARAMETER	EXAMPLE VALUE
R _{REF}	1 Ω

8.2.2.2 Detailed Design Procedure

Obtain the maximum current, I_{Qmax}, that passes through the LEDs by Equation 4:

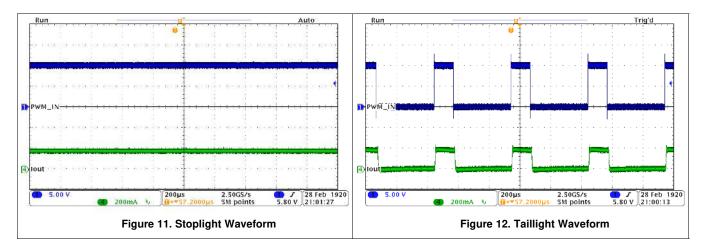
$$I_{Qmax} = \frac{V_{REF}}{R_{REF}}$$
(4)

For example, if R_{REF} equals 1 Ω , as V_{REF} is a fixed value range from 168 mV to 185 mV, I_{Qmax} should be 168 mA to 185 mA.

Figure 10 shows the application circuit of the stoplight and taillight including an automotive-qualified timer, TLC555-Q1, the duty cycle of which is programmable by two external resistors. One can see that driving the STOP signal high pulls the PWM pin constantly high, creating 100% duty cycle. Thus the LEDs operate at full brightness. When the TAIL signal is high, the LEDs operate at 25% brightness because the TLC555-Q1 timer is programmed at a fixed duty cycle of 25%.



8.2.2.3 Application Curves





9 Power Supply Recommendations

It is recommended to put a $4.7-\mu F$ ceramic capacitor on the input pin. Also a $0.1-\mu F$ bypass capacitor can be put at input pin for noise filtering. Input voltage should be between 4.5 V and 42 V.

10 Layout

10.1 Layout Guidelines

In order to prevent thermal shutdown, T_J must be less than 150° C. If the input voltage is very high, the power dissipation might be large. Currently there is the KTT (TO-263) package which has good thermal impedance, but at the same time, the PCB layout is also very important. Good PCB design can optimize heat transfer, which is absolutely essential for the long-term reliability of the device.

- Maximize the copper coverage on the PCB to increase the thermal conductivity of the board, because the
 major heat-flow path from the package to the ambient is through the copper on the PCB. Maximum copper is
 extremely important when there are not any heat sinks attached to the PCB on the other side of the package.
- Add as many thermal vias as possible directly under the package ground pad to optimize the thermal
 conductivity of the board.
- All thermal vias should be either plated shut or plugged and capped on both sides of the board to prevent solder voids. To ensure reliability and performance, the solder coverage should be at least 85 percent.

10.2 Layout Example

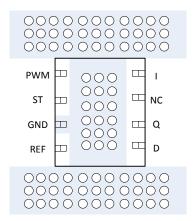


Figure 13. TL4242-Q1 WSON Board Layout Diagram



Layout Example (continued)

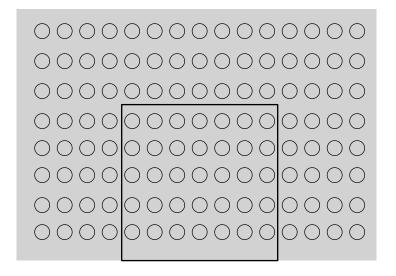




Figure 14. TL4242-Q1 TO-263 Board Layout Diagram

10.3 Thermal Considerations

This device operates a thermal shutdown (TSD) circuit as a protection from overheating. For continuous normal operation, the junction temperature should not exceed the thermal-shutdown trip point. If the junction temperature exceeds the thermal-shutdown threshold, the output turns off. When the junction temperature falls below the thermal-shutdown threshold, the output turns on again.

Calculate the power dissipated by the device according to Equation 5:

$$P = (V_I - V_O) \times I_O + V_I \times I_Q$$
(5)

In the formula, V_I represents the input voltage of the device, V_O stands for the output voltage, I_O means the output current of the LEDs, and I_O is the quiescent current dissipated by the device. The very small value of I_O sometimes allows one to neglect it.

After determining the power dissipated by the device, calculate the junction temperature from the ambient temperature and the device thermal impedance.

$$T_{J} = T_{A} + R_{\theta JA} \times P \tag{6}$$



11 Device and Documentation Support

11.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

11.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.3 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

11.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.5 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most-current data available for the designated devices. This data is subject to change without notice and without revision of this document. For browser-based versions of this data sheet, see the left-hand navigation pane.



PACKAGE OPTION ADDENDUM

10-Dec-2020

PACKAGING INFORMATION

www.ti.com

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TL4242QKTTRQ1	ACTIVE	DDPAK/ TO-263	KTT	7	500	RoHS & Green	SN	Level-3-245C-168 HR	-40 to 125	TL4242Q	Samples
TL4242TDRJRQ1	ACTIVE	SON	DRJ	8	3000	RoHS & Green	NIPDAU	Level-3-260C-168 HR	-40 to 105	4242T	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

10-Dec-2020

OTHER QUALIFIED VERSIONS OF TL4242-Q1:

NOTE: Qualified Version Definitions:

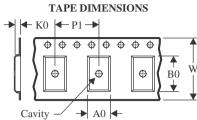
• Catalog - TI's standard catalog product

PACKAGE MATERIALS INFORMATION

www.ti.com 3-Jun-2022

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

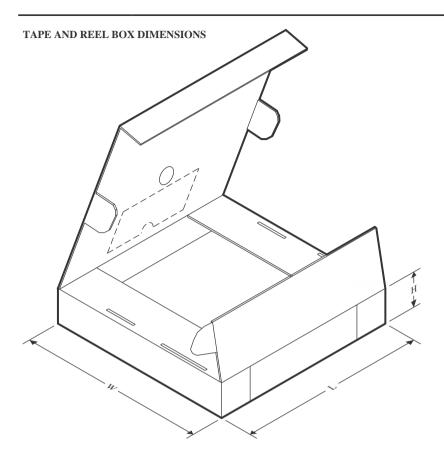


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TL4242QKTTRQ1	DDPAK/ TO-263	KTT	7	500	330.0	24.4	10.6	15.8	4.9	16.0	24.0	Q2
TL4242TDRJRQ1	SON	DRJ	8	3000	330.0	12.4	4.25	4.25	1.15	8.0	12.0	Q2

PACKAGE MATERIALS INFORMATION

www.ti.com 3-Jun-2022

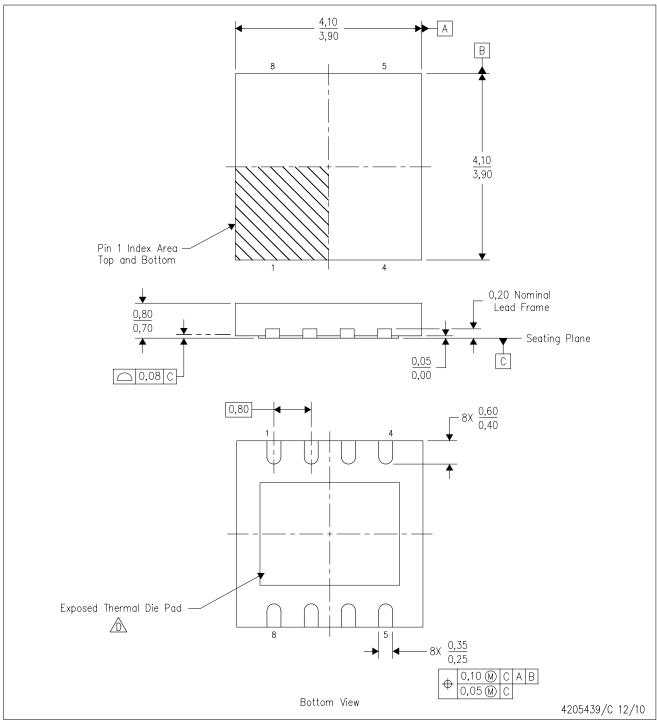


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TL4242QKTTRQ1	DDPAK/TO-263	ктт	7	500	340.0	340.0	38.0
TL4242TDRJRQ1	SON	DRJ	8	3000	356.0	356.0	35.0

DRJ (S-PWSON-N8)

PLASTIC SMALL OUTLINE NO-LEAD



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.

- B. This drawing is subject to change without notice.
- C. SON (Small Outline No-Lead) package configuration.

The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.

E. Package complies to JEDEC MO-229 variation WGGB.



DRJ (S-PWSON-N8)

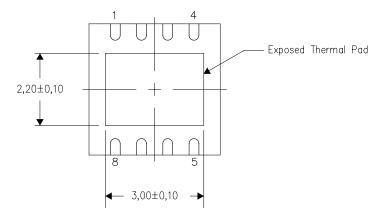
PLASTIC SMALL OUTLINE NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

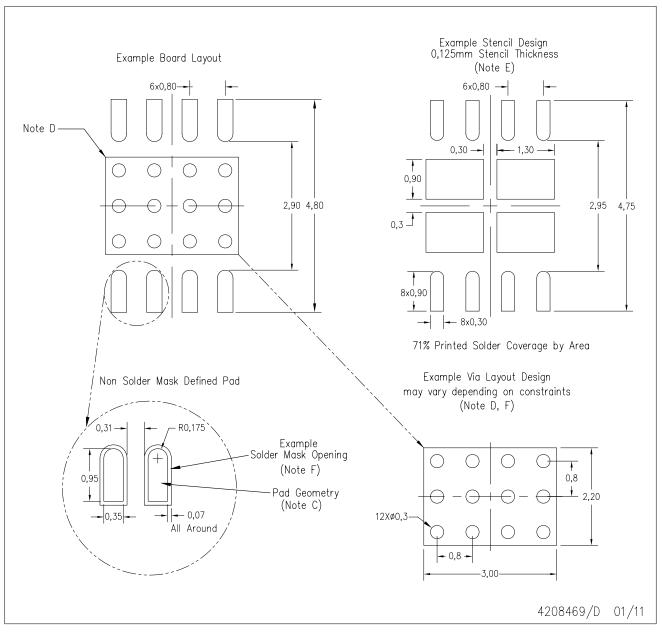
4206882/F 01/11

NOTE: All linear dimensions are in millimeters



DRJ (S-PWSON-N8)

SMALL PACKAGE OUTLINE NO-LEAD



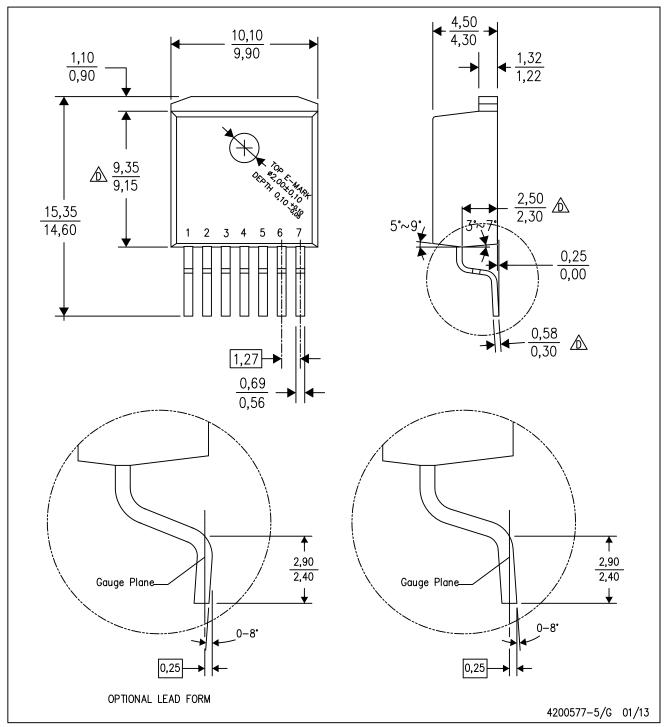
NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com https://www.ti.com.
- E. Laser cutting apertures with electropolish and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for solder mask tolerances and vias tenting recommendations for vias placed in the thermal pad.



KTT (R-PSFM-G7)

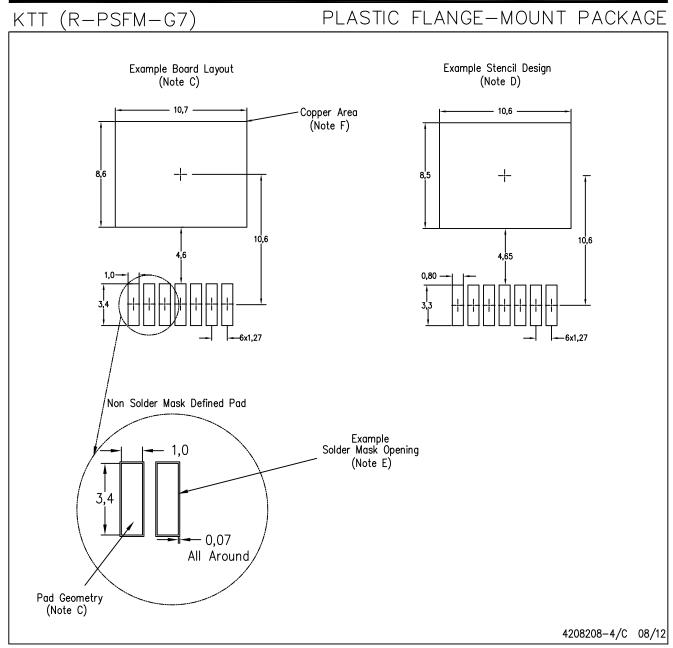
PLASTIC FLANGE-MOUNT PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash or protrusion not to exceed 0,13 per side.
- Falls within JEDEC TO-263 AB.





NOTES: A.

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-SM-782 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release.

 Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.
- F. This package is designed to be soldered to a thermal pad on the board. Refer to the Product Datasheet for specific thermal information, via requirements, and recommended thermal pad size. For thermal pad sizes larger than shown a solder mask defined pad is recommended in order to maintain the solderable pad geometry while increasing copper area.



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